

1N4148

FEATURES

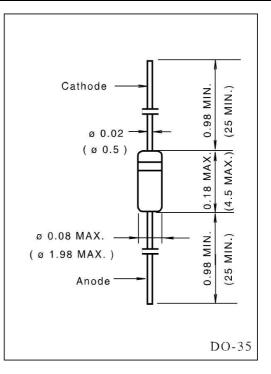
- Silicon Epitaxial Planar Diode
- Fast switching diode
- This diode is also available in other case styles including: the SOD-123 case with the type designation 1N4448W, the MiniMELF case with the type designation LL4448, and the SOT23 case with the type designation

MECHANICAL DATA

- Case: DO-35
- Weight: apprax: 0.13gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

• Ratings at 25°C ambient temperature unless otherwise specified



	Symbol	Value	Unit		
Reverse Voltage	V _R	75	V		
Peak Reverse Voltage	V _{RM}	100	V		
Rectified Current (Average) Half Wave Rectification with Resist. Load at $T_{amb} = 25$ °C and f ≥ 50 Hz	Ι _Ο	150 ¹⁾	mA		
Surge Forward Current at t < 1 s and $T_j = 25 \text{ °C}$	I _{FSM}	500	mA		
Power Dissipation at T _{amb} = 25 °C	P _{tot}	500 ¹⁾	mW		
Junction Temperature	Тj	175	°C		
Storage Temperature Range	Τ _S	-65 to +175	°C		
¹⁾ Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature (DO-35)					

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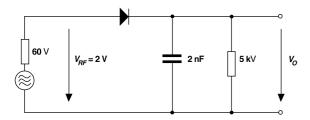
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ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Min.	Тур.	Max.	Unit
Forward Voltage at I _F = 10 mA	V _F	_	-	1	V
Leakage Current at $V_R = 20 V$ at $V_R = 75 V$ at $V_R = 20 V$, $T_j = 150 °C$	I _R I _R I _R			25 5 50	nA μA μA
Capacitance at V _F = V _R = 0 V	C _{tot}	_	-	4	pF
Voltage Rise when Switching ON tested with 50 mA Pulses $t_p = 0.1 \ \mu s$, Rise Time < 30 ns, $f_p = 5$ to 100 kHz	V _{fr}	-	-	2.5	V
Reverse Recovery Time from $I_F = 10$ mA to $I_R = 1$ mA, $V_R = 6$ V, $R_L = 100 \Omega$	t _{rr}	-	-	4	ns
Thermal Resistance Junction to Ambient Air	R _{thJA}	-	-	350 ¹⁾	K/W
Rectification Efficiency at f = 100 MHz, V_{RF} = 2 V	ην	0.45	-	-	-
¹⁾ Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature (DO-35)					



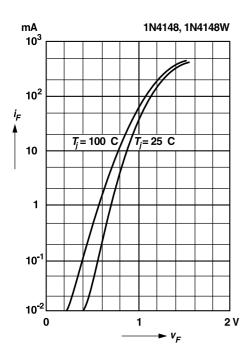
Rectification Efficiency Measurement Circuit

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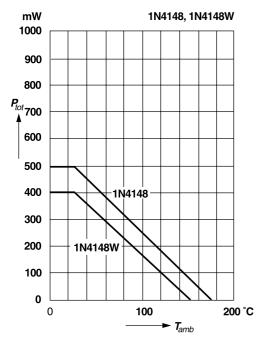


RATINGS AND CHARACTERISTIC CURVES 1N4148

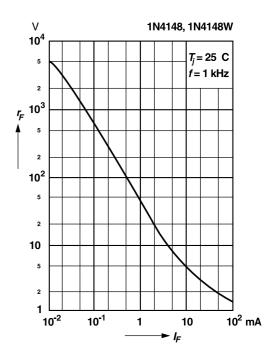
Forward characteristics



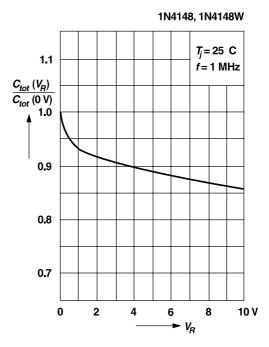
Admissible power dissipation versus ambient temperature For conditions, see footnote in table "Absolute Maximum Ratings"



Dynamic forward resistance versus forward current



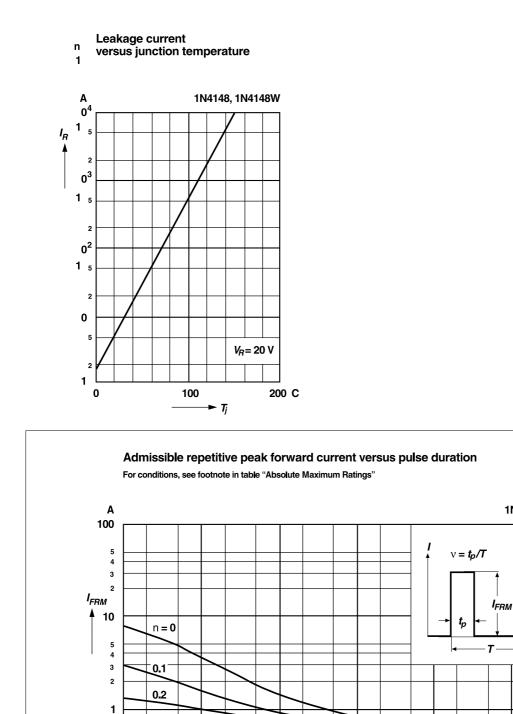
Relative capacitance versus reverse voltage



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RATINGS AND CHARACTERISTIC CURVES 1N4148



0.5

5 10⁻⁴ 2

0.1 10⁻⁵ 2

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5 10⁻² 2

► t_p

⁵ 10⁻¹ ²

5

2

1

⁵ 10 s

5 10⁻³ 2

1N4148, 1N4148W

 $T = 1/f_p$